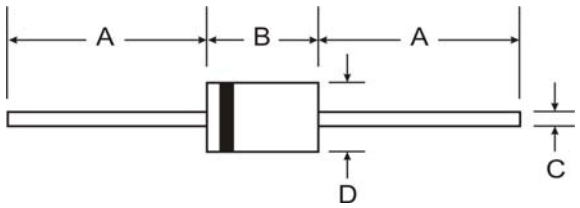
UF1001 - UF1007

1.0A ULTRA-FAST RECTIFIER

Features

- Diffused Junction
- Ultra-Fast Switching for High Efficiency
- Low Reverse Leakage Current
- Surge Overload Rating to 30A Peak
- **IEC 61000-4-2 (ESD - 150pF/330Ω)**
  UF1001 – UF1003: Contact: discharge - ±**15kV**
- **Lead Free Finish, RoHS Compliant (Note 4)**



DO-41		
Dim	**Min**	**Max**
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

Mechanical Data

- Case: DO-41
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Tin. Plated Leads Solderable per MIL-STD-202, Method 208 e3
- Polarity: Cathode Band
- Marking: Type Number
- Ordering Information: See Page
- Weight: 0.35 grams (approximate)

Maximum Ratings and Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	UF 1001	UF 1002	UF 1003	UF 1004	UF 1005	UF 1006	UF 1007	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 5)	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T_A = 55°C (Note 1)	I_O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I_{FSM}	30							A
Forward Voltage @ I_F = 1.0A	V_{FM}	1.0			1.3	1.7			V
Peak Reverse Current @ T_A = 25°C at Rated DC Blocking Voltage (Note 5) @ T_A = 100°C	I_{RM}	5.0 100							μA
Reverse Recovery Time (Note 3)	t_{rr}	50				75			ns
Typical Total Capacitance (Note 2)	C_T	20				10			pF
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	95							°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							°C

Notes:
1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.
4. RoHS revision 13.2.2003. High temperature solder exemption applied, see *EU Directive Annex Note 7*.
5. Short duration pulse test used to minimize self-heating effect.

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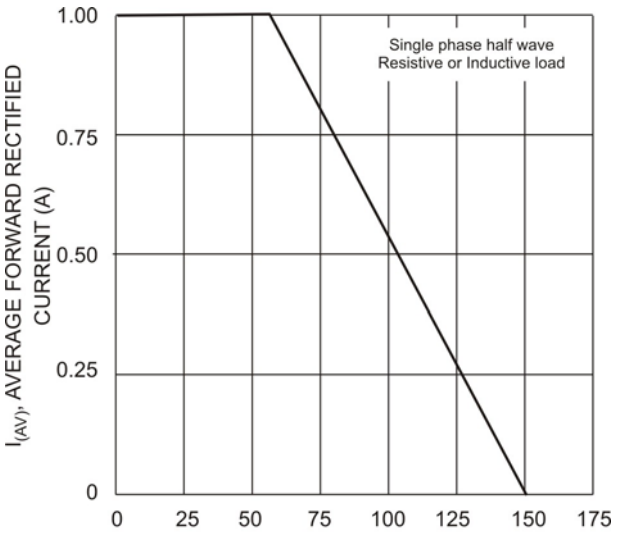


Fig. 1 Forward Current Derating Curve

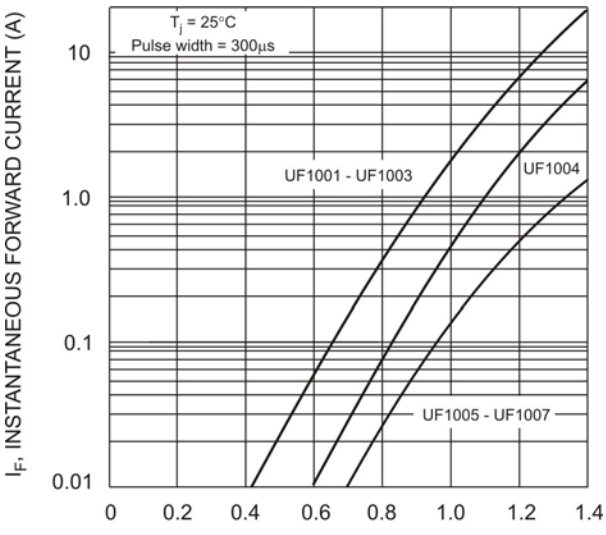


Fig. 2 Typical Forward Characteristics

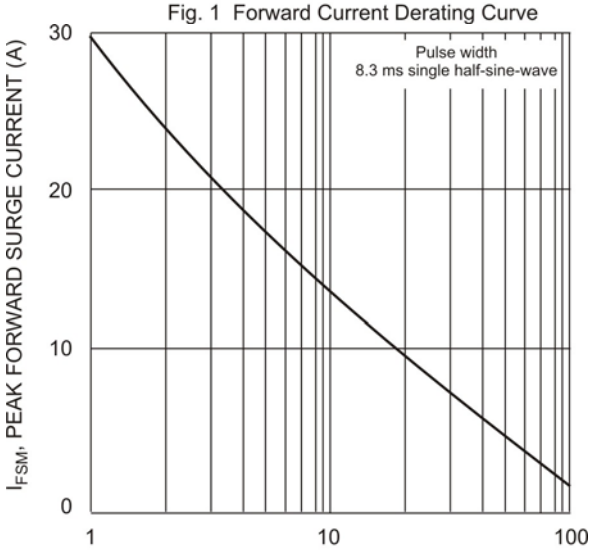


Fig. 3 Peak Forward Surge Current

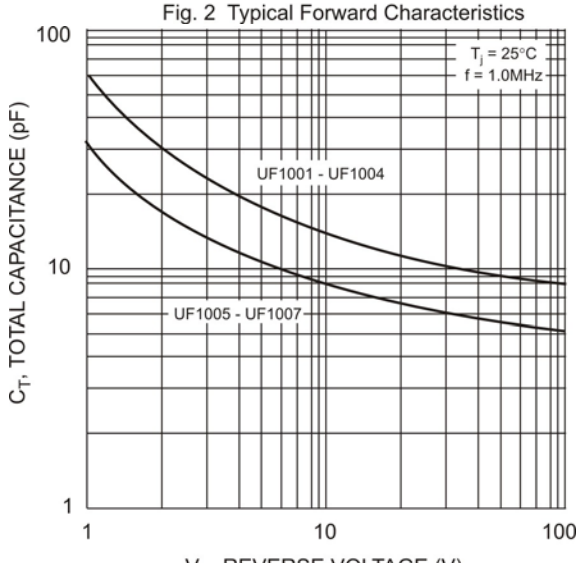
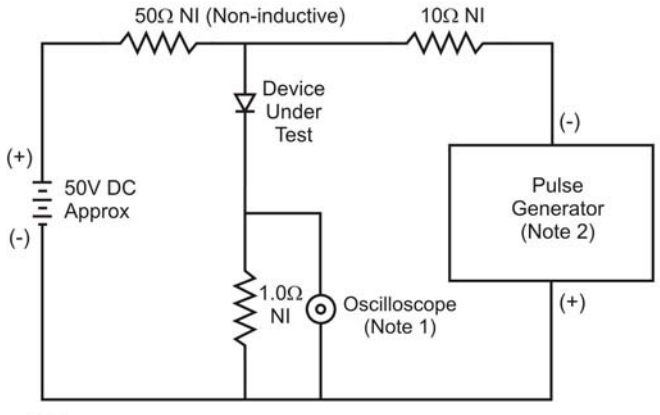


Fig. 4 Typical Total Capacitance



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.

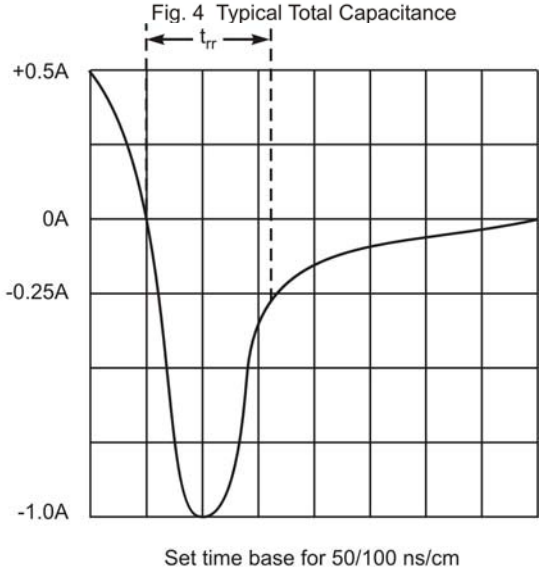


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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Ordering Information (Note 6)

Device	Packaging	Shipping
UF1001-A	DO-41	5K/Ammo Pack
UF1001-B	DO-41	1K/Bulk
UF1001-T	DO-41	5K/Tape & Reel, 13-inch
UF1002-A	DO-41	5K/Ammo Pack
UF1002-B	DO-41	1K/Bulk
UF1002-T	DO-41	5K/Tape & Reel, 13-inch
UF1003-A	DO-41	5K/Ammo Pack
UF1003-B	DO-41	1K/Bulk
UF1003-T	DO-41	5K/Tape & Reel, 13-inch
UF1004-A	DO-41	5K/Ammo Pack
UF1004-B	DO-41	1K/Bulk
UF1004-T	DO-41	5K/Tape & Reel, 13-inch
UF1005-A	DO-41	5K/Ammo Pack
UF1005-B	DO-41	1K/Bulk
UF1005-T	DO-41	5K/Tape & Reel, 13-inch
UF1006-A	DO-41	5K/Ammo Pack
UF1006-B	DO-41	1K/Bulk
UF1006-T	DO-41	5K/Tape & Reel, 13-inch
UF1007-A	DO-41	5K/Ammo Pack
UF1007-B	DO-41	1K/Bulk
UF1007-T	DO-41	5K/Tape & Reel, 13-inch

Notes: 6. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02008.pdf.

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